SG6203



Synchronous Rectifier Controller for Flyback Converter

FEATURES

- Low operation current (1.7mA)
- One resistor for timing setting
- Internal automatic tracking for optimum dead time
- No reverse energy flow at light load
- Best suited for primary green-mode PWM IC
- Wide supply voltage range from 6V to 20V
- Built-in 18V Zener diode
- Optional current sensing:
 - Current shunt
 - RC network for better efficiency

APPLICATIONS

Flyback converters, such as:

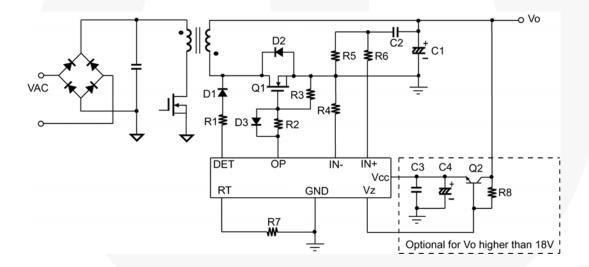
- Power adaptors
- Open-frame SMPS

DESCRIPTION

The SG6203 is designed to control and drive the synchronous rectifier for the flyback converter. The synchronous signal of the primary switch is obtained by a single diode connected between the transformer secondary winding and the SG6203. Using the SG6203, no additional transformer winding is required and the circuit complexity can be minimized.

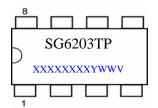
The power unit can be properly operated under discontinuous conduction mode (DCM) or continuous conduction mode (CCM). Problems such as "shoot-through" or "cross conduction" in CCM and energy-reverse from the secondary to the primary in DCM are prevented by the SG6203 design.

TYPICAL APPLICATION

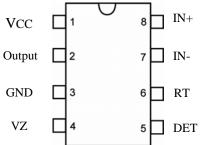




MARKING DIAGRAMS



T: D=DIP, S=SOP
P: Z=Lead Free + ROHS
Compatible
XXXXXXXX: Wafer Lot
Y: Year; WW: Week
V: Assembly Location



PIN CONFIGURATION

ORDERING INFORMATION

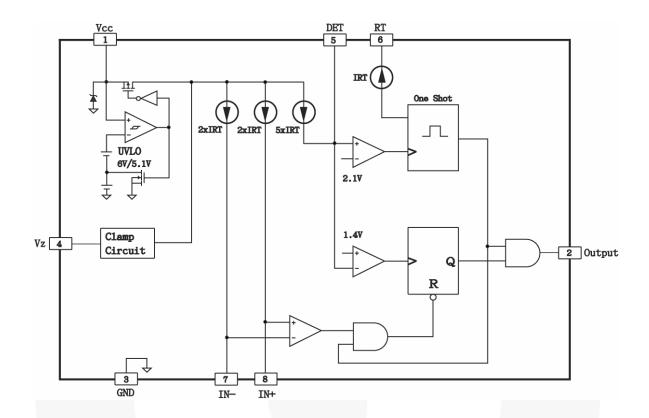
Part Number	Pb-Free	Package
SG6203SZ		8-Pin SOP
SG6203DZ	(8-Pin DIP

PIN DESCRIPTIONS

Pin	Name	Function
1	Vcc	Supply voltage of gate driver and control circuits.
2	Output	Totem-pole output to drive the synchronous power MOSFET. When the voltage on DET pin falls below 1.4V from above 2.1V, the synchronous MSOFET is turned on. To prevent the reversed energy flow, this pin is disabled once the voltage on IN+ pin is lower than that of IN- pin or the internal one-shot timer is terminated.
3	GND	The power ground and signal ground. A 0.1µF decoupling capacitor placed between VCC and GND is recommended.
4	VZ	Built-in 18V Zener diode. When the flyback output voltage is higher than 18V, this pin can be used to provide a stable 18V to VCC pin. If the flyback output voltage is lower than 18V, this pin can be left open and the output voltage connected directly to VCC pin.
5	DET	Connecting a diode from this pin to the transformer secondary winding provides on/off information of the primary switch. Low DET level indicates the secondary rectifier is conducted, therefore the synchronous MOSFET should be turned on. DET stays high when the primary switch is conducting or secondary rectifier turns off and the synchronous MOSFET should be turned off.
6	RT	Current reference. Connecting a resistor from this pin to ground can program the internal current reference I_{RT} . Three internal current sources, which are I_{IN+} , I_{IN-} , and I_{DET} , are then mirrored from I_{RT} . I_{RT} determines the duration of the internal one-shot signal, then the maximum on-time of the synchronous MOSFET is obtained by subtracting the on-time of the primary switch from the one-shot signal duration. If the resistor is too small, the synchronous MOSFET may be turned off even when the secondary rectifier is still conducting, which decreases the system efficiency. However, if the resistor is too large, the output is shut off immediately once DET gets high. In SG6203, an internal phase-locked-loop (PLL) modulates the duration of the internal one-shot signal to maintain a suitable dead time between the primary switch and the synchronous MOSFET.
7	IN-	The inverting input of the current sense comparator. In discontinuous conduction mode, the secondary rectifier turns off before the next switching cycle of the primary switch. Once the secondary rectifier is off, the synchronous MOSFET must be turned off to prevent the reversed energy flow. A resistor connected between IN+ and IN- can used to develop the zero current crossing signal of the secondary rectifier. Once the voltage on IN+ is lower than IN-, the output is pulled low.
8	IN+	The non-inverting input of the current sense comparator. In discontinuous conduction mode, the secondary rectifier turns off before the next switching cycle of the primary switch. Once the secondary rectifier is off, the synchronous MOSFET must be turned off to prevent the reversed energy flow. A resistor connected between IN+ and IN- can used to develop the zero current crossing signal of the secondary rectifier. Once the voltage on IN+ is lower than IN-, the output is pulled low.



BLOCK DIAGRAM





ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit	
V _{CC}	DC Supply Voltage*		25	V
l _{out}	Gate Output Current		500	mA
V _H	DET, OUT, VZ		-0.3 to 25.0	V
V _L	RT, IN+, IN-		-0.3 to 7.0	V
P _D	Davies Discipation	SOP8	400	\0/
	Power Dissipation	DIP8	800	mW
D	T. 15 (1 4)		208.4	0000
R ₀ JA	Thermal Resistance (Junction-to-Air)	DIP8	82.5	°C/W
T _J	Operating Junction Temperature		150	°C
T _{STG}	Storage Temperature Range		-65 to +150	°C
TL	Lead Temperature (Soldering, 10 Seconds)			°C
ESD	Electrostatic Discharge Capability, Human Body Model	2.0	KV	
	Electrostatic Discharge Capability, Machine Model			V

^{*} All voltage values, except differential voltages, are given with respect to GND pin.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V _{CC}	DC Supply Voltage	<20	V
T _A	Operating Ambient Temperature	-30~85	°C
R _T	Pulse Width of the One-shot Signal	12~36	ΚΩ

ELECTRICAL CHARACTERISTICS

 $V_{CC}=12V$; $R_{T}=24K\Omega$; $T_{A}=25^{\circ}C$, unless otherwise noted.

Timing Control Section

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
V _{RT}	Voltage on RT Pin		1.14	1.20	1.26	V
T _{RT}		R _T =12KΩ	6.5	7.5	8.5	μs
	Pulse Width of the One-shot Signal	R _T =24KΩ	13	15	17	μs
		R _T =36KΩ	19.5	22.5	25.5	μs
△ T _{RT}	Adjustable Range of the Pulse Width Compared to T _{RT}	$R_T=12K\Omega$; $R_T=24K\Omega$; $R_T=36K\Omega$	+40	+60	+80	%
T_DEAD	Timing Margin Between Output Turn-off (Output Falling) and Next Switching Cycle Start (DET Rising)		200		1000	ns

^{*} Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device.



SG6203

Synchronous Detection Section

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
V _{TH}	Threshold Voltage to Enable One-shot Signal 1.9		1.9	2.1	2.3	٧
V_{TL}	Threshold Voltage to Enable Output	IN+ - IN- > 5mV	1.2	1.4	1.6	V
I _{DET}	Current Output from DET Pin	R _τ =24KΩ		250	300	μΑ
T _{D_LOW}	Debounce Time from DET Low to Enable Output		150		300	ns

Current Detection Section

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
V _{OFFSET}	Offset Voltage				10	mV
I _{IN+}	Current Output from IN+	R _T =24KΩ	90	100	110	μΑ
I _{IN-}	Current Output from IN-	R _T =24KΩ	90	100	110	μΑ
I _{IN+} - I _{IN-}	Differential Current of IN+ and IN-	12KΩ < R _T < 36KΩ			1.5	μΑ
T _P	Propagation Delay (OUTPUT from Low to High)	DET< V _{TL} , IN+ - IN- > 5mV			200	ns
PSRR	Power Supply Rejection Ratio			65		dB
CMRR	Common Mode Rejection Ratio			65		dB
CMRR-f	Common Mode Rejection Ratio at 70KHz			32		dB

Zener Section

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
Vz	Zener Voltage	I _{VZ=} 0.1 ~ 3mA	18	19	20	V

Output Section

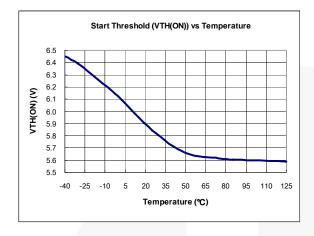
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
V _{OH}	Output Voltage High	V _{CC} =12V, I _{SOURCE} =50mA	11.2			V
	Output Voltage High	V _{CC} =6V, I _{SOURCE} =30mA	3.5			V
V _{OL}	Output Voltage Low	V _{CC} =12V, I _{SINK} =50mA		A	1	V
v OL	Output Voltage Low	V _{CC} =6V, I _{SINK} =30mA			1.2	V
Tr	Rising Time	$T_A=25$ °C; $C_L=5nF$, $V_{CC}=12V$		150	175	ns
Tf	Falling Time	T_A =25°C; C_L =5nF, V_{CC} =12V		150	175	ns

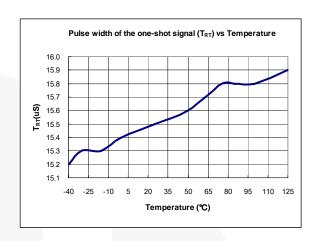
V_{CC} Section

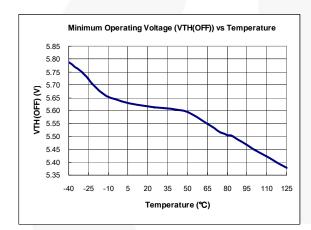
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
V _{OP}	Continuously Operating Voltage				20	V
Icc_op	Operating Current	V_{DD} =12V, Output=open, DET=50KHz, IN-=IN+=open, R_T =12K Ω		1.7	4.0	mA
V _{TH(ON)}	Start Threshold			6.0	6.3	V
V _{TH(OFF)}	Minimum Operating Voltage		4.8	5.1		V

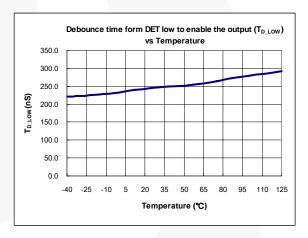


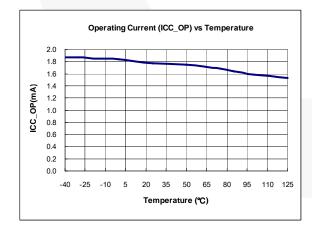
TYPICAL CHARACTERISTICS

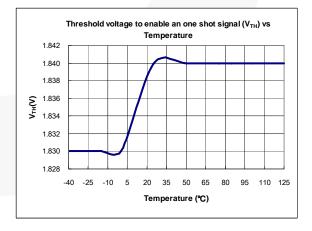




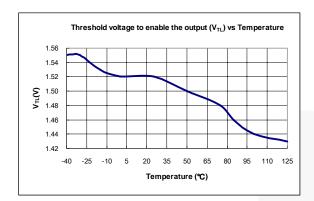














OPERATION DESCRIPTION

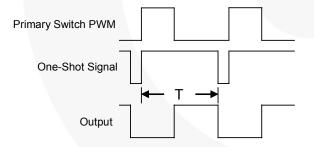
Synchronization

The DET pin provides on/off information of the primary switch. As shown in the following reference circuits, one diode connected between the DET pin and the secondary winding of the transformer is used to get this information. Low DET voltage level indicates the secondary rectifier is conducted; therefore, the synchronous MOSFET should be turned on. The voltage on DET pin stays high when the primary switch is conducting and the synchronous MOSFET should be turned off. This innovative feature requires no auxiliary winding and the circuit complexity is greatly reduced.

Anticipation and Phase Lock Loop

A resistor from the RT pin to ground is used to determine the internal current source reference. When the primary switch is turned on with DET high, an internal one-shot timer outputs high for a duration proportional to the $R_{\rm T}$ resistor. The duration of this one-shot signal can be expressed as:

$$T_{RT} = \frac{15 \times R_T(K\Omega)}{24} (\mu s)$$
 (1)



The on-time of the synchronous MOSFET is obtained by subtracting the on-time of the primary switch from the one-shot signal duration. If the resistor is too small, the synchronous MOSFET may be turned off when the secondary rectifier is still conducting, which decreases system efficiency. If the resistor is too large, the output is

shut off immediately once DET gets high. In SG6203, an internal phase locked loop modulates the duration of the internal one-shot signal to maintain a suitable dead time between the primary switch and the synchronous MOSFET. The duration of the one-shot signal can be extended 80% compared with the original value decided by $R_{\rm T}$ resistor.

Current Sense

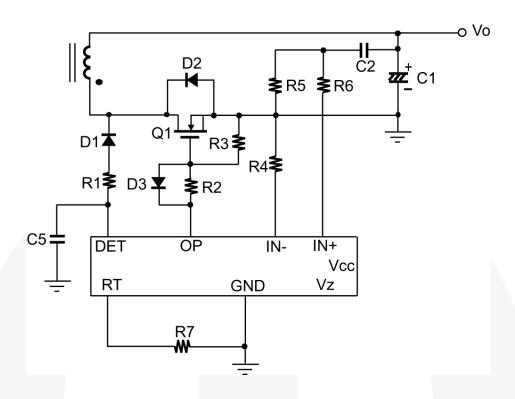
In discontinuous conduction mode, the secondary rectifier turns off before the next switching cycle of the primary switch. Once the secondary rectifier is off, the synchronous MOSFET must be turned off to prevent the reverse energy flow. Therefore, a zero current crossing detector is needed when the converter is operated under DCM. The SG6203 provides two configurations to achieve this: output capacitor ESR method (reference Circuit-A) and current-sensing resistor method (reference Circuit-B). When the secondary rectifier is turned off, the voltage on IN+ is lower than that of IN-. Once this happens, the driving signal for the synchronous MOSFET is turned off.

Under-Voltage Lockout (UVLO)

The SG6203 has an internal UVLO circuit with hysteresis. The IC is turned on if V_{CC} is higher than 6V. Once turned on, SG6203 is turned off if V_{CC} is lower than 5.1V. When the flyback output voltage is higher than 18V, the VZ pin can be used to provide a stable 18V to VCC pin.



REFERENCE CIRCUIT-A

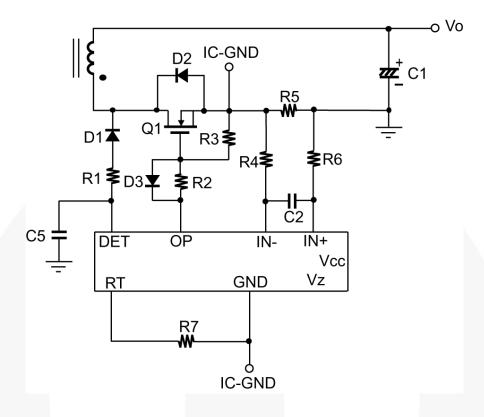


BOM

Ref Des	Part Number	Description
C2		0.1µF
C5		22pF
D1	FR102	100V/1A
D2	SB1100	100V/1A
D3	1N4148	100V/0.2A
Q1	PSMN015-110P	110V/75A; 15mΩ
R1		2.2ΚΩ
R2		22Ω
R3		47ΚΩ
R4		1.8ΚΩ
R5		2ΚΩ
R6		0
R7		16.2ΚΩ

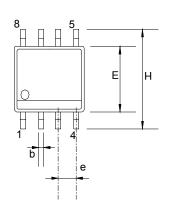


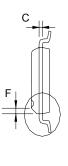
REFERENCE CIRCUIT-B

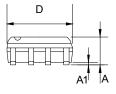


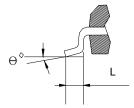


PACKAGE INFORMATION 8 PINS-SOP(S)







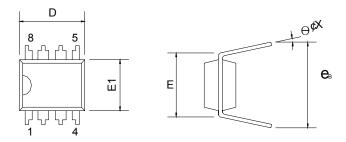


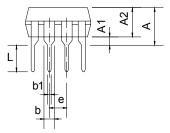
Dimensions

Symbol	Millimeter			Inch	Inch		
Symbol	Min.	Typ.	Max.	Min.	Typ.	Max.	
Α	1.346		1.752	0.053		0.069	
A1	0.101		0.254	0.004		0.010	
b		0.406			0.016		
С		0.203			0.008		
D	4.648		4.978	0.183		0.196	
E	3.810		3.987	0.150		0.157	
е	1.016	1.270	1.524	0.040	0.050	0.060	
F		0.381X45°			0.015X45°		
Н	5.791		6.197	0.228		0.244	
L	0.406		1.270	0.016		0.050	
θ°	0°		8°	O°		8°	



8PINS-DIP(D)





Dimension

Symbol	Millimeter			Inch		
	Min.	Тур.	Max.	Min.	Typ.	Max.
Α			5.334			0.210
A1	0.381			0.015		
A2	3.175	3.302	3.429	0.125	0.130	0.135
b		1.524			0.060	- 7
b1		0.457			0.018	
D	9.017	9.271	10.160	0.355	0.365	0.400
E		7.620			0.300	
E1	6.223	6.350	6.477	0.245	0.250	0.255
е		2.540			0.100	
L	2.921	3.302	3.810	0.115	0.130	0.150
ев	8.509	9.017	9.525	0.335	0.355	0.375
θ °	0°	7°	15°	0°	7°	15°







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PRODUCT STATUS DEFINITIONS

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Datasheet Identification	Product Status	Definition		
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